





SOT-23 Formed SMD Package

BCW65A, BCW65B BCW65C

GENERAL PURPOSE TRANSISTOR

N-P-N transistor

Marking

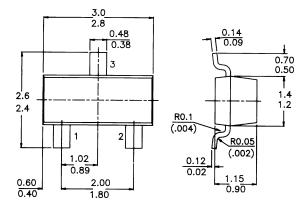
An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company

BCW65A = EA

BCW65B = EB

BCW65C = EC

PACKAGE OUTLINE DETAILS
ALL DIMENSIONS IN mm



Pin configuration

1 = BASE

2 = EMITTER

3 = COLLECTOR



ABSOLUTE MAXIMUM RATINGS		В	CW65A	65B	65C	
Collector–base voltage (open emitter)	$-V_{CBO}$	max.	60	60	60	V
Collector–emitter voltage (open base)	$-V_{CEO}$	max.	32	32	32	V
Emitter–base voltage (open collector)	$-V_{EBO}$	max.	5	5	5	V
Collector current (d.c.)	$-I_C$	max.	800	800	800	mA
Total power dissipation at $T_{amb} = 25$ °C	P_{tot}	max	225	225	225	mW
D.C. current gain						
$-I_C = 100 \text{ mA}; -V_{CE} = 10 \text{ V}$	h_{FE}	m in .	35	50	80	
$I_C = 10 \ mA; \ V_{CE} = 1 \ V$		min. max.	75 220	110	180	
$I_C = 100 \ mA; \ V_{CE} = 1 \ V$		min. max.	100 250	160 400	250 630	
$I_C = 500 \ mA; \ V_{CE} = 2 \ V$		min.	35	60	100	

BCW65A, BCW65B BCW65C

RATINGS (at $T_A = 25^{\circ}C$ unless otherwise specified) Limiting values										
Collector–base voltage (open emitter)	$-V_{CBO}$	max.	60	60	60	V				
Collector–emitter voltage (open base)	$-V_{CEO}$	max.	32	32	32	V				
Emitter-base voltage (open collector)	$-V_{EBO}$	max.	5	5	5	V				
Collector current (d.c.)	$-I_C$	max.	800	800	800	mA				
Total power dissipation at $T_{amb} = 25^{\circ}C$	P_{tot}	max	225	225	225	mW				
Storage temperature	T_{stg}			to +1		° C				
21.1.8	- 518		-							
THERMAL CHARACTERISTICS										
$T_j = P (R_{th j-t} + R_{th s-a}) + T_{amb}$										
Thermal resistance										
from junction to ambient	$R_{th j-a}$	556	556	556		°C/mW				
	,									
CHARACTERISTICS (at $T_A = 25^{\circ}\text{C}$ unless otherwise specified)										
Collector–emitter breakdown voltage										
$-I_C = 10 \ mA; I_B = 0$	$-V_{(BR)CE}$	Omin.	32	32	32	V				
Collector–base breakdown voltage										
$-I_C = 10 \text{ mA}; V_{EB} = 0$	$-V_{(BR)CE}$	5 min.	60	60	60	V				
Emitter–base breakdown voltage										
$-I_E = 10 \text{ mA}; I_C = 0$	$-V_{(BR)EBO}$	Эmin.	5	5	5	V				
Collector cut-off current										
$-V_{CE} = 32 \ V; \ I_E = 0$	$-I_{CES}$	max.	20	20	20	nA				
Emitter cut-off current										
$V_{EB} = 4 V$; $I_C = 0$	I_{EBO}	max.	20	20	20	nA				
Output capacitance at $f = 1$ MHz										
$I_E = 0; -V_{CB} = 10 \text{ V}$	C_c	max.	12	12	12	рF				
Input capacitance at $f = 100 \text{ kHz}$						•				
$I_C = 0$; $-V_{EB} = 0.5 V$	C_e	max.	80	80	80	рF				
22	Ü					•				
Saturation voltages										
$-I_C = 500 \text{ mA}; -I_B = 50 \text{ mA}$	$-V_{CEsat}$	max.	0.7	0.7	0.7	V				
$-I_C = 100 \ mA; -I_B = 10 \ mA$	-V _{CEsat}	typ.	0.3	0.3	0.3	V				
$-I_C = 500 \text{ mA}; -I_B = 50 \text{ mA}$	$-V_{BEsat}$	max.	2	2	2	V				
Noise figure at $R_S = 1 \text{ kW}$										
$-I_C = 0.2 \ mA; -V_{CE} = 5 \ V$										
f = 1 KHz, BW = 200 Hz	NF	max.	10	10	10	dB				
•										
Current Gain-Band width Product										
$I_C = 20 \text{ mA}, V_{CE} = 10V, f = 100 \text{ MHz}$	f_T	min	100	100	100	MHz				
- - ,										

Notes

Disclaimer

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